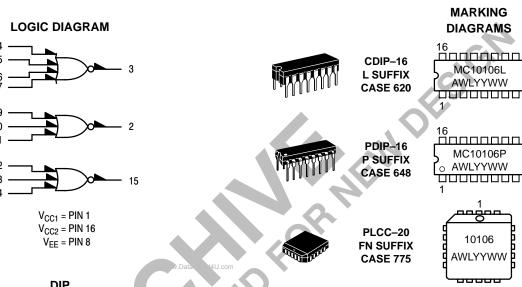
Triple 4-3-3-Input NOR Gate

The MC10106 is a triple 4–3–3 input NOR gate.

- $P_D = 30 \text{ mW typ/gate (No Load)}$
- $t_{pd} = 2.0 \text{ ns typ}$
- t_r , $t_f = 2.0$ ns typ (20%–80%)

ON Semiconductor

http://onsemi.com



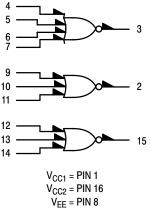
= Assembly Location

WL = Wafer Lot YY = Year

WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping		
MC10106L	CDIP-16	25 Units / Rail		
MC10106P	PDIP-16	25 Units / Rail		
MC10106FN	PLCC-20	46 Units / Rail		



DIP PIN ASSIGNMENT



Pin assignment is for Dual-in-Line Package. For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).

ELECTRICAL CHARACTERISTICS

					7	Test Limits	5			
		Pin Under	−30°C		+25°C			+85°C		
Characteristic	Symbol	Test	Min	Max	Min	Тур	Max	Min	Max	Unit
Power Supply Drain Current	Ι _Ε	8		23		17	21		23	mAdc
Input Current	I _{inH}	4		425			265		265	μAdc
	I _{inL}	4	0.5		0.5			0.3		μAdc
Output Voltage Logic 1	V _{OH}	3 2	-1.060 -1.060	-0.890 -0.890	-0.960 -0.960		-0.810 -0.810	-0.890 -0.890	-0.700 -0.700	Vdc
Output Voltage Logic 0	V _{OL}	3 2	-1.890 -1.890	-1.675 -1.675	-1.850 -1.850		-1.650 -1.650	-1.825 -1.825	-1.615 -1.615	Vdc
Threshold Voltage Logic 1	V _{OHA}	3 2	-1.080 -1.080		-0.980 -0.980			-0.910 -0.910		Vdc
Threshold Voltage Logic 0	V _{OLA}	3 2		-1.655 -1.655			-1.630 -1.630		-1.595 -1.595	Vdc
Switching Times (50Ω Load)										ns
Propagation Delay	t ₄₊₃₋ t ₄₋₃₊	3 3	1.0 1.0	3.1 3.1	1.0 1.0	2.0 2.0	2.9 2.9	1.0 1.0	3.3 3.3	
Rise Time (20 to 80%)	t ₃₊	3	1.1	3.6	1.1	2.0	3.3	1.1	3.7	
Fall Time (20 to 80%)	t ₃₋	3	1.1	3.6	1.1	2.0	3.3	1.1	3.7	

ELECTRICAL CHARACTERISTICS (continued)

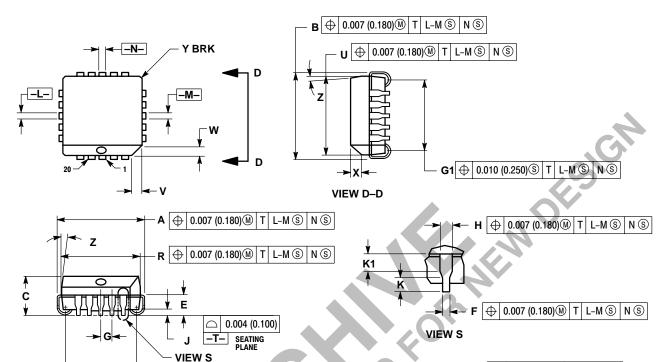
					TEST VOL	TAGE VALU	JES (Volts)		
@ Test Temperature			V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}		
–30°C			-0.890	-1.890	-1.205	-1.500	-5.2		
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
			Pin	TEST V	OLTAGE AP	PLIED TO P	INS LISTED I	BELOW	() ()
Characterist	ic	Symbol	Under Test	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}	(V _{CC}) Gnd
Power Supply Drain Cu	rrent	ш	8					8	1, 16
Input Current		I _{inH}	4	4				8	1, 16
		I _{inL}	4		4			8	1, 16
Output Voltage	Logic 1	V _{OH}	3 2					8 8	1, 16 1, 16
Output Voltage	Logic 0	V _{OL}	3 2	4 9				8 8	1, 16 1, 16
Threshold Voltage	Logic 1	V _{OHA}	3 2				4 9	8 8	1, 16 1, 16
Threshold Voltage	Logic 0	V _{OLA}	3 2			4 9		8 8	1, 16 1, 16
Switching Times	(50Ω Load)					Pulse In	Pulse Out	-3.2 V	+2.0 V
Propagation Delay		t ₄₊₃₋ t ₄₋₃₊	3 3			4 4	3 3	8 8	1, 16 1, 16
Rise Time	(20 to 80%)	t ₃₊	3			4	3	8	1, 16
Fall Time	(20 to 80%)	t ₃₋	3			4	3	8	1, 16

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to –2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

PACKAGE DIMENSIONS

PLCC-20 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 775-02 ISSUE C



NOTES:

G1 ⊕ 0.010 (0.250)③ T L-M ⑤ N ⑤

OF VICE NOT PRESCO

- IOTES:

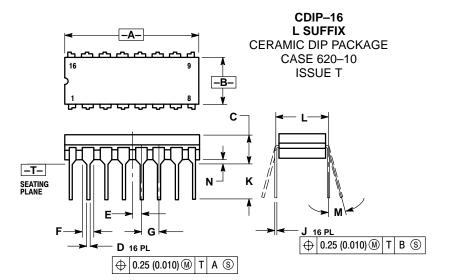
 1. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.

 2. DIMENSION 61, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

 3. DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.

 4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT
- INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIMETERS		
DIM	MIN	MIN MAX		MAX	
Α	0.385	0.395	9.78	10.03	
В	0.385	0.395	9.78	10.03	
C	0.165	0.180	4.20	4.57	
Е	0.090	0.110	2.29	2.79	
F	0.013	0.019	0.33	0.48	
G	0.050	BSC	1.27	BSC	
Н	0.026	0.032	0.66	0.81	
7	0.020		0.51		
K	0.025		0.64		
R	0.350	0.356	8.89	9.04	
5	0.350	0.356	8.89	9.04	
٧	0.042	0.048	1.07	1.21	
W	0.042	0.048	1.07	1.21	
Х	0.042	0.056	1.07	1.42	
Υ		0.020		0.50	
Z	2°	10°	2 °	10 °	
G1	0.310	0.330	7.88	8.38	
K1	0.040		1.02		



NOTES:

- ANIES.

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

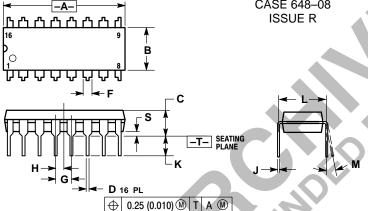
 CONTROLLING DIMENSION: INCH.

 DIMENSION L TO CENTER OF LEAD WHEN

- FORMED PARALLEL.
 DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
E	0.050	BSC	1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100	BSC	2.54 BSC		
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300	0.300 BSC		BSC 4	
M	0 °	15°	0 °	15°	
N	0.020	0.040	0.51	1.01	

PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE CASE 648-08



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIM	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10°	0°	10 °	
S	0.020	0.040	0.51	1.01	

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